# Low-power dual supply buffer/line driver; 3-state Rev. 01 — 1 July 2009

**Product data sheet** 

### **General description**

The 74AUP2T1326 is a high-performance, dual supply, low-power, low-voltage, dual buffer/line driver with output enable circuitry.

The 74AUP2T1326 is designed for logic-level translation and combines the functions of the 74AUP1G32 and 74AUP2G126. The buffer/line driver is controlled by two output enable inputs (1OE and 2OE). A logic LOW on input 1OE causes the output 2Y to assume a high-impedance OFF-state, a logic LOW on 2OE causes the output 3Y to assume a high-impedance OFF-state. The output 1Y is the result of a logic OR of the two output enable inputs.

The output enable inputs (10E and 20E) are Schmitt trigger inputs, they switch at different voltages for positive and negative-going signals. The difference between the positive voltage V<sub>T+</sub> and the negative voltage V<sub>T-</sub> is defined as the input hysteresis voltage V<sub>H</sub>. The output enable inputs accept standard input signals and are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals

Both  $V_{CC(A)}$  and  $V_{CC(B)}$  can be supplied at any voltage between 1.1 V and 3.6 V making the device suitable for interfacing between any of the low voltage nodes (1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V) with compatible input levels. Pins 10E, 20E and 1Y are referenced to  $V_{CC(A)}$  and pins A, 2Y and 3Y are referenced to  $V_{CC(B)}$ .

The device ensures low static and dynamic power consumption and is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the outputs, preventing any damaging backflow current through the device when it is powered down.

#### **Features** 2.

- Wide supply voltage range:
  - ◆ V<sub>CC(A)</sub>: 1.1 V to 3.6 V; V<sub>CC(B)</sub>: 1.1 V to 3.6 V.
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114E Class 2A exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101C exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \,\mu\text{A}$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II



#### Low-power dual supply buffer/line driver; 3-state

- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C

## 3. Ordering information

#### Table 1. Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74AUP2T1326GF	–40 °C to +85 °C	XSON10U	plastic extremely thin small outline package; no leads; 10 terminals; UTLP based; body 1 x 1.7 x 0.5 mm	SOT1081-1						

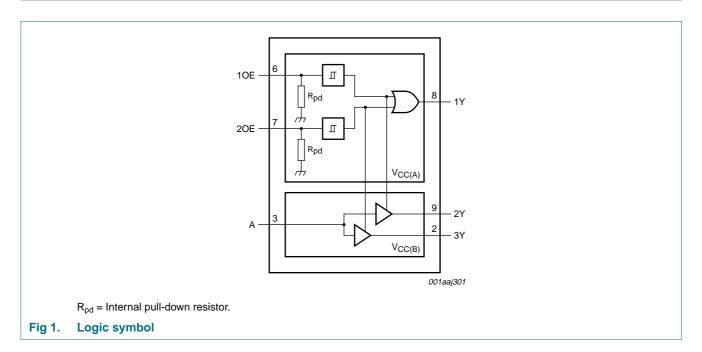
### 4. Marking

#### Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74AUP2T1326GF	pf

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

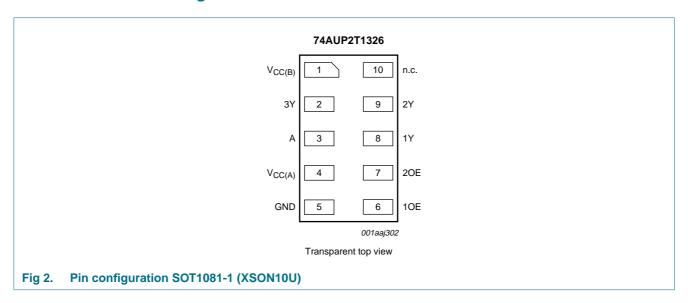
# 5. Functional diagram



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# 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
$V_{CC(B)}$	1	supply voltage B
3Y	2	data output
Α	3	data input
V <sub>CC(A)</sub>	4	supply voltage A
GND	5	ground (0 V)
10E	6	output enable input (Schmitt trigger input)
20E	7	output enable input (Schmitt trigger input)
1Y	8	data output
2Y	9	data output
n.c.	10	not connected

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## 7. Functional description

Table 4. Function table<sup>[1]</sup>

Input			Output		
10E	20E	A	1Y	2Y	3Y
L	L	X	L	Z	Z
L	Н	L	Н	Z	L
L	Н	Н	Н	Z	Н
Н	L	L	Н	L	Z
Н	L	Н	Н	Н	Z
Н	Н	L	Н	L	L
Н	Н	Н	Н	Н	Н

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

### 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+4.6	V
$V_{CC(B)}$	supply voltage B		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
$V_{I}$	input voltage		<u>[1]</u> –0.5	+4.6	V
$I_{OK}$	output clamping current	V <sub>O</sub> < 0 V	<u>[2]</u> –50	-	mA
$V_{O}$	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CCO}$	[2]	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$	[3]	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		1.1	3.6	V
$V_{CC(B)}$	supply voltage B		1.1	3.6	V
$V_{I}$	input voltage		0	3.6	V
$V_{O}$	output voltage		[1] 0	$V_{CCO}$	V

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<sup>[2]</sup> V<sub>CCO</sub> is the supply voltage associated with an output pin.

<sup>[3]</sup> For XSON10U package: above 45 °C the value of Ptot derates linearly with 2.4 mW/K.

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 Table 6.
 Recommended operating conditions ...continued

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>amb</sub>	ambient temperature		-40	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	input A; $V_{CCI} = 1.1 \text{ V to } 3.6 \text{ V}$	[2] -	200	ns/V
		input nOE; V <sub>CCI</sub> = 1.1 V to 3.6 V	[2] -	30	ms/V

<sup>[1]</sup>  $V_{CCO}$  is the supply voltage associated with an output pin.

### 10. Static characteristics

Table 7. Static characteristics

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At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			25 °C		–40 °C to	+85 °C	Unit
				Min	Тур	Max	Min	Max	V V V V V V V V V V V V V PA
V <sub>IH</sub>	HIGH-level	input A;	[1][3]						
	input	$V_{CCI} = 1.65 \text{ V to } 1.95 \text{ V}$		0.65V <sub>CCI</sub>	-	-	0.65V <sub>CCI</sub>	-	V
	voltage	$V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$		1.6	-	-	1.6	-	V
√ <sub>IL</sub>	LOW-level	input A;	[1][3]						
	input voltage	$V_{CCI} = 1.65 \text{ V to } 1.95 \text{ V}$		-	-	$0.35V_{CCI}$	-	0.35V <sub>CCI</sub>	V
	vollage	$V_{CCI}$ = 2.3 V to 2.7 V		-	-	0.7	-	0.7	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IL}$ or $V_I$ or $V_I = V_{T+}$ or $V_{T-}$							
	output voltage	$I_O = -20 \mu A;$ $V_{CCO} = 1.65 \text{ V to } 2.7 \text{ V}$	[2]	V <sub>CCO</sub> – 0.1	-	-	V <sub>CCO</sub> – 0.1	-	V
		$I_O = -3 \text{ mA}; V_{CCO} = 1.65 \text{ V}$		1.2	-	-	1.2	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CCO} = 2.3 \text{ V}$		1.97	-	-	1.97	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CCO} = 2.3 \text{ V}$		2.0	-	-	2.0	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IL}$ or $V_I$ or $V_I = V_{T+}$ or $V_{T-}$	[2]						
	output voltage	$I_O = 20 \mu A;$ $V_{CCO} = 1.65 \text{ V to } 2.7 \text{ V}$		-	-	0.10	-	0.10	V
		$I_O = 3.0 \text{ mA}; V_{CCO} = 1.65 \text{ V}$		-	-	0.45	-	0.45	V
		$I_O = 2.3 \text{ mA}; V_{CCO} = 2.3 \text{ V}$		-	-	0.33	-	0.33	V
		$I_O = 4.0 \text{ mA}; V_{CCO} = 2.3 \text{ V}$		-	-	0.40	-	0.40	V
I	input leakage current	input A; $V_I = 0 \text{ V to } 2.7 \text{ V};$ $V_{CCI} = 1.65 \text{ V to } 2.7 \text{ V}$	<u>[1]</u>	-	-	±0.1	-	±0.5	μΑ
OZ	OFF-state output current	output 2Y, 3Y; $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = 0$ V to 2.7 V; $V_{CC(A)} = 1.65$ V to 2.7 V; $V_{CC(B)} = 1.65$ V to 2.7 V		-	-	±0.1	-	±0.5	μΑ
OFF	power-off leakage current	1Y; $V_{CC(A)} = 0 \text{ V}$ ; $V_O = 0 \text{ V}$ to 2.7 V; $V_{CC(B)} = 1.65 \text{ V}$ to 2.7 V		-	-	±0.2	-	±0.5	μΑ
ataSheet	4U.com	A, 2Y, 3Y; $V_{CC(B)} = 0 \text{ V}$ ; $V_1 \text{ or } V_0 = 0 \text{ V to } 2.7 \text{ V}$ ; $V_{CC(A)} = 1.65 \text{ V to } 2.7 \text{ V}$		-	-	±0.2	-	±0.5	μΑ

<sup>[2]</sup>  $V_{CCI}$  is the supply voltage associated with an input pin.

#### Low-power dual supply buffer/line driver; 3-state

Table 7. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			25 °C		-40 °C to	+85 °C	Unit
				Min	Тур	Max	Min	Max	
$\Delta I_{OFF}$	additional power-off leakage	1Y; $V_{CC(A)} = 0 \text{ V to } 0.2 \text{ V};$ $V_O = 0 \text{ V to } 2.7 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 2.7 \text{ V}$		-	-	±0.2	-	±0.6	μА
	current	A, 2Y, 3Y; $V_{CC(B)} = 0 \text{ V to } 0.2 \text{ V};$ $V_{I} \text{ or } V_{O} = 0 \text{ V to } 2.7 \text{ V};$ $V_{CC(A)} = 1.65 \text{ V to } 2.7 \text{ V}$		-	-	±0.2	-	±0.6	μΑ
$I_{CC(A)}$	supply	$V_I = 0 \text{ V or } V_{CC(A)}; I_O = 0 \text{ A}$	<u>[1]</u>						
	current A	$V_{CC(A)} = 1.65 \text{ V to } 2.7 \text{ V};$ $V_{CC(B)} = 0 \text{ V to } 2.7 \text{ V}$		-	-	0.5	-	0.9	μΑ
I <sub>CC(B)</sub>	CC(B) supply current B	$V_I = 0 \text{ V or } V_{CC(B)}; I_O = 0 \text{ A}$	[1]						
		$V_{CC(A)} = V_{CC(B)} = 1.65 \text{ V to}$ 2.7 V;		-	-	0.5	-	0.9	μΑ
		$V_{CC(A)} = 1.71 \text{ V}; V_{CC(B)} = 2.6 \text{ V}$		-	-	500	-	750	μΑ
$\Delta I_{CC}$	additional supply	nOE; $V_{CC(A)} = V_{CC(B)} = 2.7 \text{ V};$ $V_I = V_{CC(A)} - 0.6 \text{ V}$		-	-	40	-	50	μΑ
	current	A; $V_{CC(A)} = V_{CC(B)} = 2.7 \text{ V};$ $V_1 = V_{CC(B)} - 0.6 \text{ V};$		-	-	80	-	100	μΑ
		A; $V_1$ = GND to 2.7 V; nOE = GND; $V_{CC(A)}$ = 1.65 V to 2.7 V; $V_{CC(B)}$ = 1.65 V to 2.7 V	<u>[4]</u>	-	-	2	-	2	μΑ
R <sub>pd</sub>	pull-down resistance			145	200	255	140	260	kΩ
Cı	input capacitance	input A; $V_I = 0 \text{ V or } V_{CCI}$ ; $V_{CCI} = 1.65 \text{ V to } 2.7 \text{ V}$	<u>[1]</u>	-	0.9	-	-	-	pF
		input nOE; $V_I = 0 \text{ V or } V_{CCI}$ ; $V_{CCI} = 1.65 \text{ V to } 2.7 \text{ V}$	<u>[1]</u>	-	8.0	-	-	-	pF
Co	output	1Y; $V_O = GND$ ; $V_{CCO} = 0 V$	[2] _		1.7	-	-	-	pF
	capacitance	2Y, 3Y enabled; $V_O = GND$ ; $V_{CCO} = 0 V$	[2] _		1.7	-	-	-	pF
		2Y, 3Y disabled; $V_{CCO} = 0 \text{ V to } 2.7 \text{ V};$ $V_O = \text{GND or } V_{CCO}$	[2] _		1.5	-	-	-	pF

<sup>[1]</sup>  $V_{CCI}$  is the supply voltage associated with the input pin.

<sup>[2]</sup>  $V_{CCO}$  is the supply voltage associated with the output pin.

<sup>[3]</sup> For  $V_{CCI}$  values not specified in the data sheet: minimum  $V_{IH} = 0.7 \times V_{CCI}$  and maximum  $V_{IL} = 0.3 \times V_{CCI}$ .

<sup>[4]</sup> To show  $I_{CC}$  remains very low when the input-disable feature is enabled.

Low-power dual supply buffer/line driver; 3-state

# 11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 5.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	Unit
				Min	Typ[1]	Max	Min	Max	
C <sub>L</sub> = 5 p	F								
t <sub>pd</sub>	propagation delay	A to 2Y, 3Y; see Figure 3	[2]						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		1.9	3.2	4.5	1.7	5.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	2.6	3.4	1.3	3.8	ns
		nOE to 1Y; see Figure 3							
		$V_{CC(A)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	4.0	5.4	2.2	6.0	ns
		$V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	3.2	3.9	2.0	4.3	ns
C <sub>L</sub> = 10	pF								
t <sub>pd</sub>	propagation delay	A to 2Y, 3Y; see Figure 3	[2]						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.3	3.8	5.3	2.0	5.8	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		1.8	3.2	4.1	1.5	4.5	ns
		nOE to 1Y; see Figure 3							
		$V_{CC(A)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	4.6	6.1	2.5	6.7	ns
		$V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	3.7	4.6	2.2	5.0	ns
$C_L = 5 p$	F; $V_{CC(A)} = 1.65 \text{ V to } 1.65 \text{ V}$	95 V							
t <sub>en</sub>	enable time	nOE to 2Y, 3Y; see Figure 4	[3]						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	4.4	9.7	2.1	10.1	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	3.9	8.2	1.9	8.8	ns
t <sub>dis</sub>	disable time	nOE to 2Y, 3Y; see Figure 4	<u>[4]</u>						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	4.5	8.9	2.1	9.4	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	3.8	7.8	1.9	8.4	ns
$C_L = 5 p$	F; $V_{CC(A)} = 2.3 \text{ V to } 2.7$	V							
t <sub>en</sub>	enable time	nOE to 2Y, 3Y; see Figure 4	<u>[3]</u>						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	4.0	8.7	2.1	9.0	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	3.4	7.2	1.9	7.7	ns
t <sub>dis</sub>	disable time	nOE to 2Y, 3Y; see Figure 4	<u>[4]</u>						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	4.2	7.9	2.1	8.3	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.2	3.5	6.8	1.9	7.3	ns
C <sub>L</sub> = 10	pF; V <sub>CC(A)</sub> = 1.65 V to	1.95 V							
t <sub>en</sub>	enable time	nOE to 2Y, 3Y; see Figure 4	[3]						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	4.9	11.0	2.5	11.7	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	4.4	9.7	2.2	10.5	ns
t <sub>dis</sub>	disable time	nOE to 2Y, 3Y; see Figure 4	<u>[4]</u>						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	5.6	10.8	2.5	11.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	4.6	9.5	2.2	10.1	ns

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#### Low-power dual supply buffer/line driver; 3-state

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 5.

Symbol	Parameter	Conditions			25 °C		-40 °C 1	to +85 °C	Unit
				Min	Typ[1]	Max	Min	Max	
C <sub>L</sub> = 10 p	pF; V <sub>CC(A)</sub> = 2.3 V to 2.3	7 V							
t <sub>en</sub>	enable time	nOE to 2Y, 3Y; see Figure 4	[3]						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	4.5	10.0	2.5	10.5	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	3.9	8.7	2.2	9.3	ns
t <sub>dis</sub>	disable time	nOE to 2Y, 3Y; see Figure 4	<u>[4]</u>						
		$V_{CC(B)} = 1.65 \text{ V to } 1.95 \text{ V}$		2.9	5.3	9.8	2.5	10.3	ns
		$V_{CC(B)} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	4.3	8.4	2.2	8.9	ns
$C_L = 5 pl$	F and 10 pF								
C <sub>PD</sub>	power dissipation capacitance	per active output; output 2Y, 3Y; $f_i = 1$ MHz; $V_i = 0$ V to $V_{CC}$	<u>[5]</u>						
		$V_{CC(A)} = V_{CC(B)} = 1.8 \text{ V}$		-	3.0	-	-	-	pF
		$V_{CC(A)} = V_{CC(B)} = 2.5 \text{ V}$		-	3.6	-	-	-	pF

- [1] All typical values are measured at nominal  $V_{CC(A)}$  and  $V_{CC(B)}$ .
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [4]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .
- [5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = load capacitance in pF;

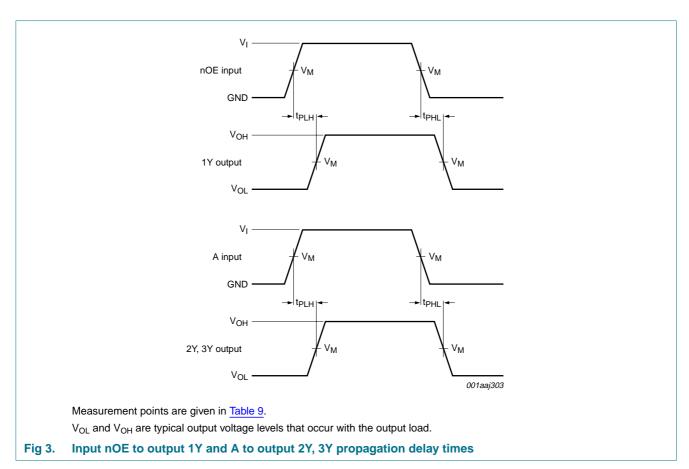
V<sub>CC</sub> = supply voltage in V;

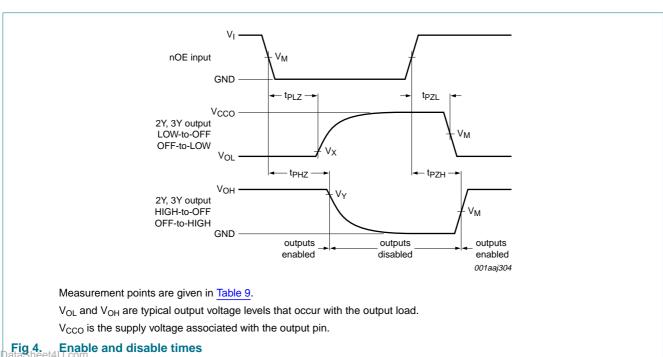
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

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#### 12. Waveforms





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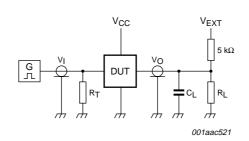
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#### Low-power dual supply buffer/line driver; 3-state

Table 9. Measurement points

Supply voltage	Input <sup>[1]</sup>	Output <sup>[2]</sup>						
V <sub>CC(A)</sub> , V <sub>CC(B)</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
1.65 V to 2.7 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V				

- [1]  $V_{CCI}$  is the supply voltage associated with the data input port.
- [2]  $V_{CCO}$  is the supply voltage associated with the output port.



Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Fig 5. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load <sup>[2]</sup>		V <sub>EXT</sub>			
V <sub>CC(A)</sub> , V <sub>CC(B)</sub>	V <sub>I</sub> [1]	$t_r = t_f$	CL	R <sub>L</sub> [3]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> [4]	
1.65 V to 2.7 V	V <sub>CCI</sub>	≤ 3.0 ns	5 pF, 10 pF	5 k $\Omega$ or 1 M $\Omega$	open	GND	2V <sub>CCO</sub>	

- [1]  $V_{CCI}$  is the supply voltage associated with the data input port.
- [2] For measuring enable and disable times,  $C_L$  and  $R_L$  are connected to pin 2Y and 3Y.
- [3] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ , for measuring propagation delays  $R_L$  = 1 M $\Omega$ .
- [4]  $V_{CCO}$  is the supply voltage associated with the output port.

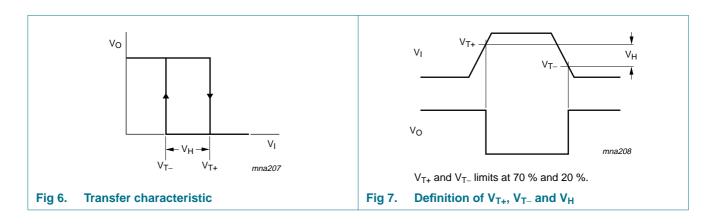
### 13. Transfer characteristics

Table 11. Transfer characteristics

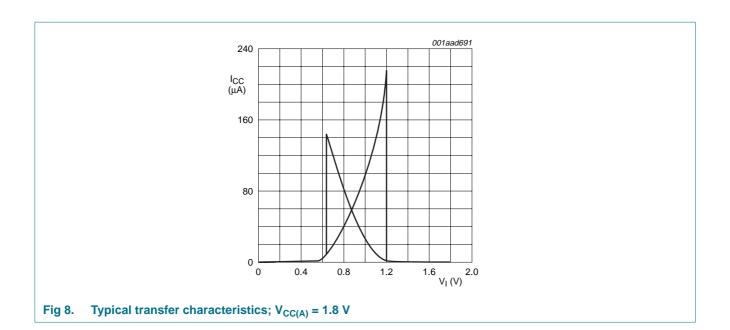
Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 5.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		Unit
			Min	Тур	Max	Min	Max	
$V_{T+}$	positive-going threshold voltage	nOE inputs; see Figure 6 and Figure 7	·					
		V <sub>CC(A)</sub> = 1.65 V	0.91	-	1.29	0.91	1.29	V
		V <sub>CC(A)</sub> = 2.3 V	1.37	-	1.77	1.37	1.77	V
V <sub>T</sub> negative-going threshold voltage	nOE inputs; see <u>Figure 6</u> and <u>Figure 7</u>							
		V <sub>CC(A)</sub> = 1.65 V	0.47	-	0.84	0.47	0.84	V
	V <sub>CC(A)</sub> = 2.3 V	0.69	-	1.04	0.69	1.04	V	
V <sub>H</sub> hysteresis voltage		nOE inputs; (V <sub>T+</sub> – V <sub>T-</sub> ); see <u>Figure 6</u> , <u>Figure 7</u> and <u>Figure 8</u>						
		V <sub>CC(A)</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	V
		V <sub>CC(A)</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	V

### 14. Waveforms transfer characteristics



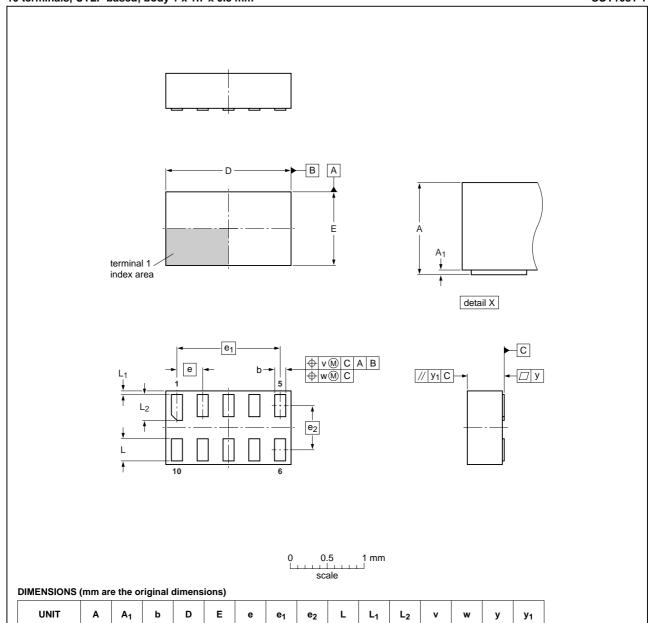
### Low-power dual supply buffer/line driver; 3-state



# 15. Package outline

XSON10U: plastic extremely thin small outline package; no leads; 10 terminals; UTLP based; body 1 x 1.7 x 0.5 mm

SOT1081-1



UN	NIT	Α	A <sub>1</sub>	b	D	E	е	e <sub>1</sub>	e <sub>2</sub>	L	L <sub>1</sub>	L <sub>2</sub>	v	w	у	У1
	max	0.50	0.05	0.20	1.8	1.1				0.4	0.10	0.45				
mm	nom	0.48	0.03	0.15	1.7	1.0	0.35	1.4	0.6	0.3	0.05	0.35	0.1	0.05	0.05	0.1
	min	0.46	0.00	0.10	1.6	0.9				0.2	0.00	0.25				

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT1081-1						<del>08-03-28</del> 08-04-18	

# Fig 9 Package outline SOT1081-1 (XSON10U)

Low-power dual supply buffer/line driver; 3-state

### 16. Abbreviations

#### Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 17. Revision history

#### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2T1326_1	20090701	Product data sheet	-	-

#### Low-power dual supply buffer/line driver; 3-state

### 18. Legal information

#### 18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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#### Low-power dual supply buffer/line driver; 3-state

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